Investigation of Indoor Stability Testing of Polymer Solar Cell

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We have fabricated organic solar cell of a new low bandgap polymer poly[4,4-bis(2-ethylhexyl)-4H-cyclopenta[2,1-b:3,4-b']dithiophene-2,6-diyl-alt-4,7-bis(2-thienyl)-2,1,3-benzothiadiazole-5',5''-diyl] (PCPDTTBTT). We have investigated for the first time the stability tests, ISOS-L-1 and ISOS-D-3, of PCPDTTBTT solar cells. Thermal annealing of PCPDTTBTT solar cells at 80°C brought about an improvement of photocurrent generation, stability, and efficiency of the solar cells. T80 value of PCPDTTBTT solar cell is about 150 hours which is close to P3HT (235 h). PCPDTTBTT is very promising polymer for both polymer solar cell efficiency and stability.

1. Introduction

Polymer solar cells (PSCs) are currently attracting a great deal of attention having already shown great promise as renewable, lightweight, and low cost energy sources [1–3]. In a molecular LEGO game, many combinations are possible for donor (D) and acceptor (A) building blocks; novel low bandgap polymers are generated and subsequently characterized. Development of low bandgap polymers can be achieved with the selection of suitable D and A segments in molecular design. Donor-donor-acceptor-donor structure (DDAD) is well known for low bandgap polymer. That structure has some solubility problems which can be improved by introducing substitution of alkyl chains. PCPDTTBTT is one of the DDAD structure copolymers. In the literature effects of position of side chains on PCPDTTBTT solar cell were studied (thin solid films). In addition PCPDTTBTT solar cells with nanocrystal quantum dots were studied [4–6].

In spite of high development potential of polymer solar cells, their stability and degradation are not studied in detail. The intrinsic reasons of degradation of organic photovoltaic are poorly understood. Studies have indicated that the degradation mechanisms in polymer solar cells include reaction with O2, H2O, and the electrode materials. Therefore, to increase the durability of polymer solar cells requires careful selection of donor, acceptor, electrode, and encapsulation materials [7, 8].

There are many parameters affecting the stability of organic solar cell. Material is very important; that is, glass transition temperature (Tg), molecular weight, HOMO-LUMO levels, and stability of polymer are very critical. Encapsulation methods mostly use UV-epoxy resins, some barrier films, and so forth, during fabrication process. The choice of encapsulation method is crucial to improve stability of solar cells. Annealing is a parameter where polymer can be annealed thermally or by solvent annealing. Architecture is also prominent which can be of normal or inverted type that leads to affecting the stability of organic solar cell.

Encapsulated organic solar cells based on small molecules (pentacene/C60) were studied based on their shelf life [9]; the devices were stable over 6000 h, while devices with no encapsulation degraded rapidly after only 10 h of air exposure. In addition, thermal annealing during fabrication of the devices improved the open-circuit voltage and power conversion efficiency of the solar cells. Krebs and Spanggaard [10] also studied stability of polymer solar cells, and the lifetime of polymer solar cells over 10,000 h was achieved. However, the device performance is too low.
OPV systems may have failure modes other than inorganic systems including photooxidation and chemical degradation of the electrodes and interfaces [11]. For this reason, a new set of guidelines are being developed, which aim to compare data and claims obtained by different laboratories. The complexity of developing testing procedures to measure durability stems from the fact that unlike inorganic technologies organic photovoltaic is a highly diverse technology with cells that can be prepared with different architecture, using many different materials. All these variables affect overall stability performance of the final device. Enhancement of stability of organic photovoltaic can be achieved through packaging and encapsulation or other means that empirically remove the problem or reduce it as much as possible. To figure out the problem, a plot of the power conversion efficiency over time can be taken before ending with device degradation. The time of operation until 80% (T80) and 50% (T50) of the initial performance is extracted for a device exhibiting a linear decay. An agreement has to be made on how decay data have to be evaluated and reported. For that reason, the guidelines of OPV stability protocols have been presented in ISOS meetings [12]. The purpose is to provide reasonable accuracy in the comparison of reported stability and lifetime data for organic solar cells produced from polymers and small molecules.

Significant progressing polymer solar cells have been made by the synthesis of low band gap conjugated polymers and optimization of the device preparation conditions, including the application of adjusting the volume fractions of the components [1, 13], thermal annealing treatments [14, 15], and solvent annealing [16, 17].

The commercialization of polymer solar cells needs greatly the understanding of the degradation phenomena such as recrystallization and temperature variations, as well as reactions during oxidation and reduction. The understanding of degradation mechanism will lead to the development of novel materials, efficient polymer solar cells encapsulation, and the alternative barrier layers which are more resistant to oxygen and water.

In this study, we investigate new low band gap polymer PCPDTTBTT that is not studied in detail in literature. We have firstly studied stability testing of PCPDTTBTT solar cells, ISOS-L-1 and ISOS-D-3. PCPDTTBTT is very promising polymer for both polymer solar cell efficiency and stability.

### 2. Experimental

#### 2.1. Materials

PCPDTTBTT donor material (Figure 1) was purchased from Luminescence Coop. Hole transport layer, poly(3,4-ethylenedioxythiophene) (PEDOT) doped with poly(styrene sulfonic acid) (PSS) (PEDOT:PSS Clevios P), w as obtained from Heraeus and n-type semiconductor phenyl-C61-butyric acid methyl ester (PC61BM) was purchased from Sigma-Aldrich (Figure 1). PCPDTTBTT and PCBM solutions with 20 mg/mL concentration were prepared by using 1,2-dichlorobenzene from Alfa Aesar. The active layer solutions were prepared by mixing the PCPDTTBTT polymer and PCBM in 1:3 blend ratio.

#### 2.2. Fabrication of Polymer Solar Cells

PCPDTTBTT devices were fabricated on glass substrates with the following structure: indium thin oxide (ITO)/PEDOT:PSS/PCPDTTBTT:PC61BM/Ca/Al. The ITO coated glass substrates with sheet resistance of 15 Ω/sq. were ultrasonically cleaned in detergent, acetone, isopropyl alcohol, and deionized water, successively for 5 min, and then dried under nitrogen flow. The dried ITO substrates were transferred into an UV-ozone cleaner to create a hydrophilic ITO surface. PEDOT:PSS solution was spin-coated onto glass substrates and annealed at 130 °C for 10 min.

Then the blends were spin-coated onto the PEDOT:PSS coated substrates (Figure 2) and annealed at different temperatures of 80 °C, 100 °C, and 120 °C for 10 min. Finally, Ca (10 nm)/Al (70 nm) was deposited by thermal vacuum evaporation in a vacuum of about 1 × 10−6 mbar. The active area of the cell was 0.09 cm². The encapsulation of the polymer solar cell was performed by using Osilla UV curing epoxy resin.

#### 2.3. Characterization

The current density-voltage (J-V) characteristics of devices were taken under light illumination using standard solar irradiation of 100 mW/cm² (AM1.5G) with xenon lamp as a light source and computer-controlled voltage-current Keithley 2600 source meter at 25 °C under ambient atmosphere. Morphology of the blend films was investigated with noncontact mode by Atomic Force Microscopy (AFM) (Park Systems). UV-Vis spectroscopic measurements were performed by using a PG Instruments T80 model UV-Vis spectrophotometer.
Table 1: Effects of thermal annealing of PCPDTTBTT solar cells on photovoltaic parameters.

<table>
<thead>
<tr>
<th>PCPDTTBTT solar cells</th>
<th>$V_{OC}$ (V)</th>
<th>$J_{SC}$ (mA/cm$^2$)</th>
<th>FF</th>
<th>PCE (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>No annealing</td>
<td>0.58 ± 0.01</td>
<td>4.83 ± 0.5</td>
<td>0.38 ± 0.01</td>
<td>1.08 ± 0.08</td>
</tr>
<tr>
<td>Thermal annealing at 80°C</td>
<td>0.59 ± 0.01</td>
<td>5.71 ± 0.5</td>
<td>0.39 ± 0.01</td>
<td>1.34 ± 0.08</td>
</tr>
<tr>
<td>Thermal annealing at 100°C</td>
<td>0.60 ± 0.01</td>
<td>4.81 ± 0.5</td>
<td>0.37 ± 0.01</td>
<td>1.08 ± 0.08</td>
</tr>
<tr>
<td>Thermal annealing at 120°C</td>
<td>0.61 ± 0.01</td>
<td>5.45 ± 0.5</td>
<td>0.39 ± 0.01</td>
<td>1.30 ± 0.08</td>
</tr>
</tbody>
</table>

3. Results and Discussion

PCPDTTBTT devices which were fabricated on glass substrates and indoor stability of the polymer solar cells were studied. Current density-voltage characteristics of PCPDTTBTT solar cells were depicted in Figure 3. Effect of annealing was investigated on PCPDTTBTT solar cells. Table 1 summarizes effects of thermal annealing of PCPDTTBTT solar cells on photovoltaic parameters. Thermal annealing provided improvement of current density of PCPDTTBTT solar cells. When PCPDTTBTT solar cell was annealed at 80°C, the current densities and power conversion efficiencies of PCPDTTBTT solar cells increased compared to PCPDTTBTT solar cell without annealing (Figure 3). The effects of annealing temperature on PCPDTTBTT solar cells were summarized in Table 1.

UV spectra of PCPDTTBTT:PC$_{61}$BM blend films on glass substrate: A: without thermal annealing, B: thermal annealing at 80°C, C: thermal annealing at 100°C, and D: thermal annealing at 120°C. It is observed that considering the absorption of PCPDTTBTT:PC$_{61}$BM blend films there are two absorbance maxima which are 518 and 643 nm. Absorption of all PCPDTTBTT:PC$_{61}$BM blend films with thermal annealing indicated that absorption values are enhanced which means that photon harvesting increased. Furthermore, annealing also leads to red shift (645 nm–657 nm) in the UV absorbance maxima which means conjugation length is increased.

IPCE values of PCPDTTBTT solar cells with various annealing temperatures which were fabricated at 80°C, 100°C, and 120°C are presented in Figure 5. The best result for photocurrent generation was obtained in PCPDTTBTT solar cells with thermal annealing at 80°C. All thermal annealing conditions indicated that thermal annealing improved photocurrent generation (Figure 5). IPCE plot showed that the photocurrent generation at 80°C is greater than in the other
temperatures. IPCE and $J$ and $V$ results indicated that the optimum temperature for annealing seems to be at 80°C.

3.1. Stability Tests of PCPDTTBT Solar Cells. There are several categories of stability testing of OPV devices such as tests under dark, simulated light, and humidity and at outdoor conditions. Each degradation test [18] is divided into three categories: basic (1), intermediate (2), and advanced (3) levels. The main variables of the experiments are temperature, light, humidity, and environment. In this study, the solar cells were tested with ISOS-L-1 and ISOS-D-3 testing protocols.

For accurate comparison of indoor stability testing in real life, a light source that closely matches spectral distribution of daylight has to be chosen. Xenon arc is very good match to AM 1.5G with correct filter. Since lamp aging tends to affect more the UV range than other ranges, monitoring in UV range is critical to maintain proper irradiance level. For indoor testing, ISOS-L-1 [12] was carried out to understand degradation of organic solar cells. The brief history of testing protocols was given in Table 2.

Device structure is ITO/PEDOT:PSS/PCPDTTBT:PCBM/ Ca:Al. There was no annealing during fabrication of PCPDTTBT. For this device ISOS-L-1 testing (Figure 6(a)) indicated that the normalized $V_{OC}$ is very stable during 500 h; however normalized $J_{SC}$ decreased to 40% durability. After 100 h, efficiency decreased to 50% durability; it was very significant change, and then it decreases slightly. After 400 h, the efficiency decreased gradually to 20% durability.

Stability of $V_{OC}$ values of PCPDTTBT solar cell was investigated in Figure 6(a). It is showed that all devices showed very good stability in respect to $V_{OC}$. Meanwhile with PCPDTTBT solar cell 80°C thermal annealing indicated 100% durability in 500 h under AM 1.5G solar simulator.

### Table 2: Properties of ISOS-L-1 and ISOS-D-3 protocols.

<table>
<thead>
<tr>
<th>Characterization light source</th>
<th>ISOS-L-1</th>
<th>ISOS-D-3</th>
</tr>
</thead>
<tbody>
<tr>
<td>Light source</td>
<td>Simulator</td>
<td>None</td>
</tr>
<tr>
<td>Temperature</td>
<td>Ambient</td>
<td>65°C</td>
</tr>
<tr>
<td>Relative humidity</td>
<td>Ambient (low)</td>
<td>85% (chamber)</td>
</tr>
</tbody>
</table>

Normalized $J_{SC}$ plot shows that stability of PCPDTTBT solar cell 80°C thermal annealing is the best one since current density stability is 70% in 500 hours under AM1.5G solar simulator (Figure 6(b)). Stability of PCPDTTBT solar cell 100°C thermal annealing is also better than others. It is about 60% durability of normalized $J_{SC}$ (Figure 6(b)). Stability of FF of PCPDTTBT solar cell is affected by annealing conditions (Figure 6(c)). The device structure with 80°C thermal annealing showed the best FF values which are 70%. In 500 hours under AM1.5G solar simulator when it is increased to 120°C, stability of FF of PCPDTTBT solar cell decreased to 50% in 500 h under AM 1.5G solar simulator (Figure 6(c)). Figure 6(d) depicted that PCPDTTBT solar cell with thermal annealing at 80°C has 50% durability in 500 h.

ISOS-D-3 stability testing of PCPDTTBT indicated that two devices showed very good stability with respect to $V_{OC}$. The former is PCPDTTBT solar cell without thermal annealing and the latter is PCPDTTBT solar cell with 80°C thermal annealing. Normalized $J_{SC}$ and time plot of ISOS-D-3 testing showed 50% durability in 400 hours for PCPDTTBT solar cell without thermal annealing and stability of PCPDTTBT solar cell at 80°C thermal annealing (Figure 7(b)). Normalized efficiency and time plot of ISOS-D-3 study of PCPDTTBT solar cell is depicted in Figure 7(d). It is indicated that stability of PCPDTTBT solar cell without thermal annealing and stability of PCPDTTBT solar cell with 80°C thermal annealing are very close to each other and also have higher durability than stability of PCPDTTBT solar cell with 100°C and 120°C thermal annealing.

It is concluded that when PCDTTBT film is annealed at higher temperatures that can cause some detrimental effect in the film, these places, for example, some dark points, can lead to faster degradation and so decrease the device performance. These dark points can be seen in AFM images in Figure 8(d).

PCPDTTBT:PCBM blends were spin-coated onto the glass substrates and annealed at different temperatures of 80°C, 100°C, and 120°C for 10 min. AFM pictures have been taken and compared with respect to morphology. AFM photographs of PCPDTTBT:PCBM blends at annealed different temperatures of 80°C, 100°C, and 120°C for 10 min are depicted in Figure 8. Roughness of the film without annealing was about 3.75 ± 0.5 nm. AFM of PCPDTTBT:PCBM blends without annealing indicated that the grain sizes are about 90 ± 5 nm; there are also small dark spots. The roughness of PCPDTTBT:PCBM blends with 80°C annealing is about 4.00 ± 0.5 nm and the grain size is about 100 ± 5 nm (Figure 8(b)). AFM of PCPDTTBT:PCBM blends at...
annealed 100 °C showed that grain sizes are about 120 ± 5 nm. The roughness of PCPDTTBTT:PCBM blends with 100 °C annealing is about 3.90 ± 0.5 nm (Figure 8(c)). AFM of PCPDTTBTT:PCBM blends at annealed 120 °C showed that some dark points which lead to leakage are current. They are of different dimensions, a width of 150 ± 5 nm and depth of 3 ± 0.5 nm (Figure 8(d)). The morphology is rather different than the other temperature; grains which are spoiled dark spots are larger than in the other temperatures. The roughness of PCPDTTBTT:PCBM blends with 120 °C is about 2.90 ± 0.5 nm.

4. Conclusion

In conclusion, we have fabricated four different solar cells, one as a reference cell that was fabricated without annealing. When PCPDTTBTT solar cell was annealed at 80 °C, the current densities and power conversion efficiencies of PCPDTTBT solar cells increased compared to PCPDTTBTT solar cell without annealing. Thermal annealing with 80 °C seems to be optimum temperature for the PCPDTTBTT solar cells. Considering the absorption of PCPDTTBTT:PCBM blend films, there are two absorbance maxima which are 518 and
Absorption of all PCPDTTBTT:PCBM blend films with thermal annealing indicated improved absorption values so photon harvesting increased. UV spectrum of PCPDTTBTT:PCBM blend films with 80°C annealing showed that best absorbance’s values are increased with annealing with 80°C compared to PCPDTTBTT:PCBM blend film without annealing. ISOS-L-1 study of PCPDTTBTT:PCBM solar cells with 80°C thermal annealing indicated that thermal annealing had improved stability of PCPDTTBTT solar cell. Normalized efficiency increased to 50% durability from 20% durability during 500 h. $T_{80}$ value of PCPDTTBTT solar cell changed drastically from 10 hours to 150 hours. $T_{80}$ value of P3HT (commercial polymer) and solar cell $T_{80}$ value are 235 h [19–21], so the results are indicating that PCPDTTBTT is very promising material since stability is very close to P3HT. In addition, PCPDTTBTT solar cell showed 70% durability after 250 h in ISOS-L-1 tests. Accelerated aging tests at 85°C and ISOS-D-3 test also indicated that the stability of PCPDTTBTT solar cells under prolonged thermal and moisture stress is about 400 h.
Figure 8: AFM topography spectra of PCPDTTBT:PCBM blends annealed at different temperatures of 80°C, 100°C, and 120°C for 10 min. 2\( \mu \)m \( \times \) 2\( \mu \)m scan size: (a) no annealing, (b) being annealed at 80°C, (c) being annealed at 100°C, and (d) being annealed at 120°C; AFM 3D spectra of PCPDTTBT:PCBM blends annealed at different temperatures: (e) no annealing, (f) being annealed at 80°C, (g) being annealed at 100°C, and (h) being annealed at 120°C.
The results showed that the stability of this polymer is good and can be improved with novel encapsulation techniques, for example, atomic layer deposition (ALD) or novel barrier materials.

Competing Interests
The authors declare that they have no competing interests.

References